# SP6030 High Performance Synchronous Rectifying Converter

### DESCRIPTION

SP6030 is a high performance and tightly integrated secondary side synchronous rectifier for switching mode power supply system. It combines a much lower voltage drop N-channel MOSFET to emulate the traditional diode rectifier at the secondary side of Flyback converter, The fundamental of SP6030 synchronous rectifier (SR) driver IC is based on our U.S. patented methods that utilize the principle of "prediction" logic circuit. The IC deliberates previous cycle timing to control the SR in present by "predictive" algorithm that makes adjustments to the turn-off time, in order to achieve maximum efficiency and avoid cross-conduction at the same time. The SP6030 is capable to adapt in almost all existing Resonance converters with few adjustments considered necessary.

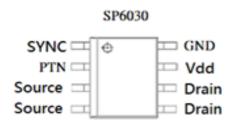
#### **FEATURES**

- Offers efficiency improvement over Schottky Diode (depends on drive configuration of the SR).
- Low Standby Power to meet DOE Lot 6 requirement.
- Secondary-side synchronous rectifier optimized for output system.
- Build-in 45V SR MOSFET with low Rdson
- Operating frequency up to 300 KHz.
- Synchronize to transformer secondary voltage waveform.
- Internal over voltage protection

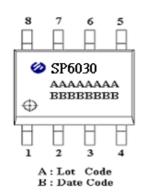
#### APPLICATIONS

- Switching Mode Power Supply (CCM&DCM&QR)
- Storage area network power supplies
- Telecommunication converters
- Embedded systems
- Industrial & commercial systems using high current processors
- Power converters to meet Lot 6 requirement

## PIN CONFIGURATION (SOP-8)

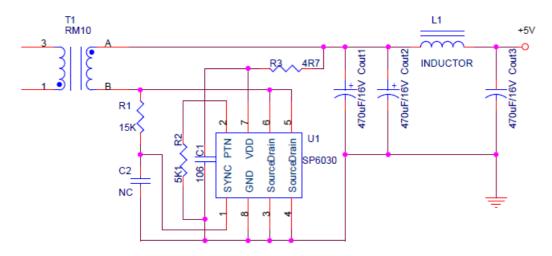


#### **PART MARKING**

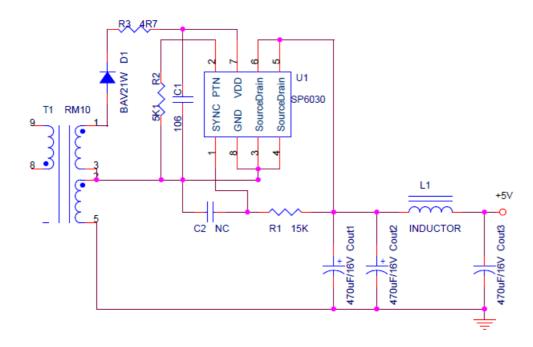


# TYPICAL APPLCATION CIRCUIT

## SP6030\_application circuit\_L/S



# SP6030\_application circuit\_H/S with AUX winding



# **PIN DESCRIPTION**

Pin	Symbol	Description		
1	SYNC	Synchronized signal from Vds of SR MOSFET		
2	PTN	Connecting a resistor to ground to set the dead time and dynamic trigger point		
3	Source	Internal MOSFET Source		
4	Source	Internal MOSFET Source		
5	Drain	Internal MOSFET drain		
6	Drain	Internal MOSFET drain		
7	Vdd	DC supply voltage.		
8	GND	Ground connection.		

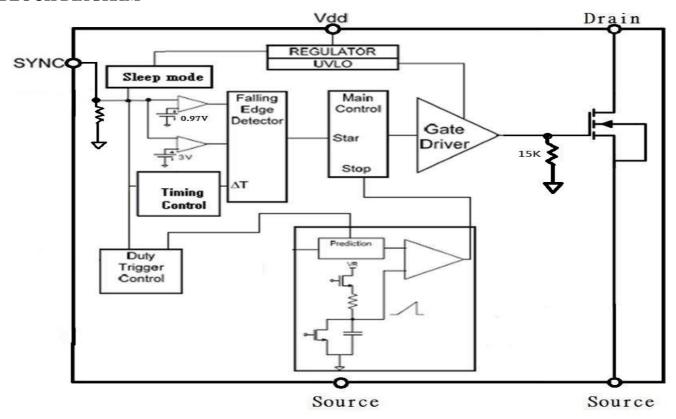
# **ORDERING INFORMATION**

Part Number	Package	Part Marking		
SP6030S8RGB	SOP-8	SP6030		

<sup>※</sup> SP6030S8RGB : Tape Reel ; Pb − Free ; Halogen - Free

2020/06/30 **Ver 2** 

# **BLOCK DIAGRAM**



### **ABSOULTE MAXIMUM RATINGS** (TA=25°C, unless otherwise specified.)

The following ratings designate persistent limits beyond which damage to the device may occur.

Symbol	Parameter	Value	Unit	
$V_{dd}$	DC Supply Voltage	16	V	
Vd to Vs	Drain to Source	45	V	
P <sub>D</sub>	Power Dissipation @ T <sub>A</sub> =85°C (*)	0.3	W	
$T_{\rm J}$	Operating Junction Temperature Range	-40 to125	$^{\circ}\!\mathbb{C}$	
$T_{STG}$	Storage Temperature Range	-40 to 150	$^{\circ}\!\mathbb{C}$	
$T_{LEAD}$	Lead Soldering Temperature for 5 sec.	260	$^{\circ}\!\mathbb{C}$	

### THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
Rөja	Thermal Resistance-Junction to Ambient (*)	110	°C/W

<sup>(\*)</sup> The power dissipation and thermal resistance are evaluated under copper board mounted with free air conditions.



### **ELECTRICAL CHARACTERISTICS**

 $(T_A=25^{\circ}\text{C}, V_{dd}=5\text{V}, Freq. =50 \text{ KHz}, Duty Cycle=50\%, unless otherwise specified.})$ 

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
SUPPLY INPUT	1					
Idd	Supply current	No load & Sleep mode		0.2	0.35	mA
		VSYNC=Vdd ,No load	2.0	3.0	4.0	mA
Vdd	Supply voltage	Idd peak < 1A	4.3		16	V
Vdd on	Enable voltage		3.35	3.7	4.1	V
Vdd hysteresis	Enable voltage			0.2		V
Vovp	Over voltage protection		17	17.5	18.5	V
V <sub>OVP</sub> hysteresis	Enable voltage			0.67		V
SYNC REFERE	NCE (SYNC)					
Vshth	SYNC high threshold			3.0		V
Vslth	SYNC low threshold			0.9		V
Vsync	SYNC clamp voltage	Isync=3mA	Vdd+1.5			V
Vsync WK	SYNC wake-up voltage	Pulse width >1uS for Vdd=5V	6			V
Isync	SYNC input current				3	mA
Dynamic Protect						
Dt	Dynamic variable			5.1		uS
Ton-min	MOSG-C on time	PWM adjusts time > Dt	0.4		0.7	uS
SR MOSFET SE	CCTION					
BVdss	MOSFET Drain-Source Breakdown	VGS=0V,ID=250uA	45			V
	Voltage					
D1()	Drain-Source On-Resistance	VGS=10V,ID=15A		7.5	9.5	mΩ
Rds(on)		VGS=4.5V,ID=8A		10	14	
Ciss	Input Capacitance			942		pF
Coss	Output Capacitance	VDS=20V, VGS=0V		309		
Crss	Reverse Transfer Capacitance f=1MHz			29		1 ' '
Td(on)	Turn On Time	VDD=20V, ID=10A, VGS=10V		6		<del>  _</del>
Td(off)				21		nS

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